



Product Summary

BV _{DSS}	Rds(on)	I _D T _A = +25°C
	0.99Ω @ V _{GS} = 4.5V	0.5A
20V	1.2Ω @ V _{GS} = 2.5V	0.45A
	1.8Ω @ V _{GS} = 1.8V	0.37A
	2.4Ω @ V _{GS} = 1.5V	0.32A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Power-management functions
- Backlighting
- Load switches

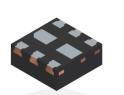
Features

- Low On-Resistance
- Low Input/Output Leakage
- Fast Switching Speed
- **ESD** Protected Gate •
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) •
- Halogen and Antimony Free. "Green" Device (Note 3) .
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

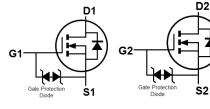
- Package: X2-DFN1010-6
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0015 grams (Approximate)

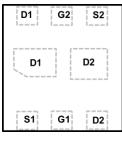




X2-DFN1010-6 (Type UXC)

Bottom View





Equivalent Circuit

Pin-Out Top View

Ordering Information (Note 4)

Part Number	Paakaga	Topo Width (mm)	Tape Pitch (mm)	Packing		
Fait Nulliper	Package	ackage Tape Width (mm)	Tape Filch (min)	Qty.	Carrier	
DMN2991UDR4-7	X2-DFN1010-6 (Type UXC)	8	4	5000	Tape & Reel	
DMN2991UDR4-7R	X2-DFN1010-6 (Type UXC)	8	4	5000	Tape & Reel	

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

	BQ = Product Type Marking Code YWX = Date Code Marking YWX YWX W = Week (ex: 4 = 2024) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)					
DMN2991UDR4-7	BQ YWX Pin 1 Pin 1					
DMN2991UDR4-7R	XMA BQ = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 4 = 2024) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday) Pin 1 XMA XMA XMA					

Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	2	3	4	5	6	7	8	9	0	1	2	3
Week 1-26			27-52				53					
Code	A-Z				a-z			Z				
Internal Code	Sun Mon		Tue	W	ed	Thu		Fri		Sat		
Code	Т		U		V	V	V	Х		Y		Z



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	Vdss	20	V		
Gate-Source Voltage	Vgss	±8	V		
Continuous Drain Current (Note 5) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +100°C	ID	0.5 0.4	А
Maximum Continuous Body Diode Forward Currer	Is	0.4	A		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	Ідм	1.4	A		

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.38	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	331	°C/W
Total Power Dissipation (Note 6)		PD	0.7	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	180	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)					•		
Drain-Source Breakdown Voltage	BV _{DSS}	20			V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	—	1	μA	$V_{DS} = 16V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±10	μA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	0.4	—	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		—	0.5	0.99		$V_{GS} = 4.5V, I_D = 100mA$	
Static Drain-Source On-Resistance	Descent	_	0.6	1.2	Ω	$V_{GS} = 2.5V, I_D = 50mA$	
Static Drain-Source On-Resistance	Rds(on)	—	0.7	1.8		V _{GS} = 1.8V, I _D = 20mA	
		—	0.9	2.4		$V_{GS} = 1.5V, I_D = 10mA$	
Diode Forward Voltage	Vsd	—	0.8	1.0	V	$V_{GS} = 0V$, $I_{S} = 150mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	14.6	—			
Output Capacitance	Coss	—	4.7	_	pF	V _{DS} = 16V, V _{GS} = 0V f = 1.0MHz	
Reverse Transfer Capacitance	Crss	—	3.2			1 - 1.00012	
Total Gate Charge	Qg	—	0.28				
Gate-Source Charge	Qgs	—	0.04		nC	$V_{GS} = 4.5V, V_{DS} = 10V$ ID = 250mA	
Gate-Drain Charge	Q _{gd}	—	0.1			10 – 20011A	
Turn-On Delay Time	td(on)	—	7.1				
Turn-On Rise Time	tR	—	18			$V_{DD} = 10V, V_{GS} = 4.5V$	
Turn-Off Delay Time	t _{D(OFF)}	—	125		ns	$R_L = 47\Omega, R_G = 10\Omega$ ID = 200mA	
Turn-Off Fall Time	tF	_	56.9	_			

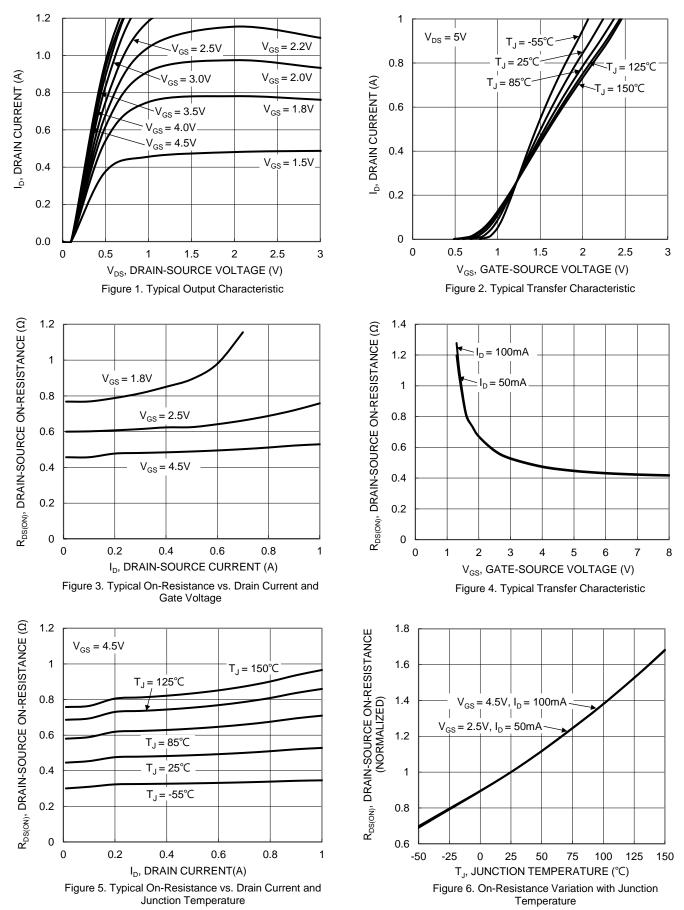
Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.

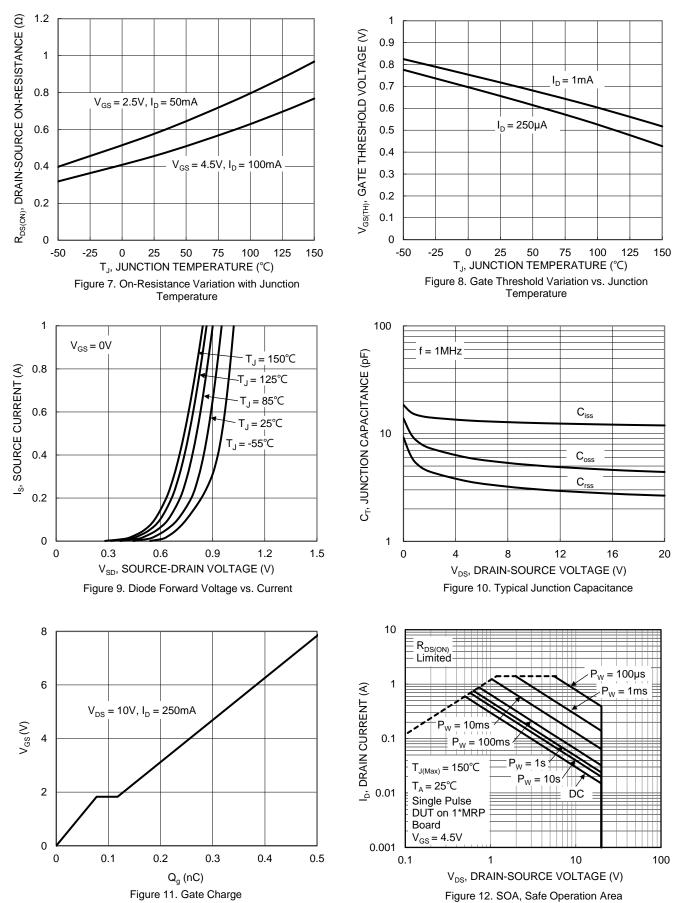


DMN2991UDR4



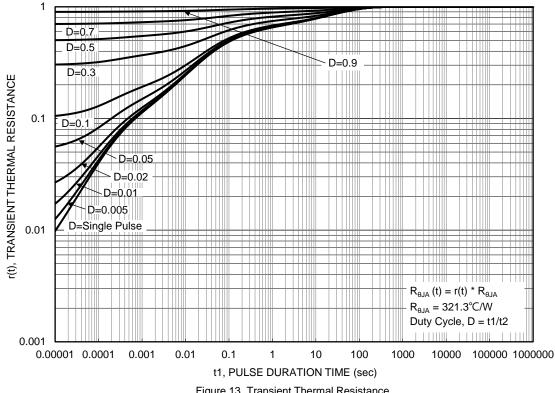


DMN2991UDR4



DMN2991UDR4 Document number: DS44515 Rev. 4 - 2



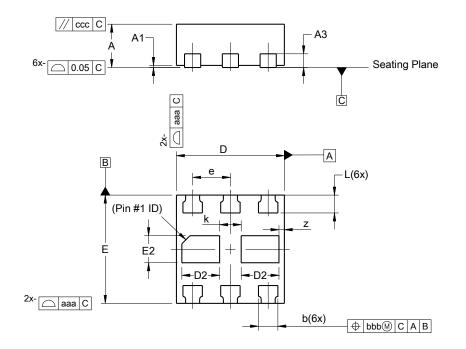






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



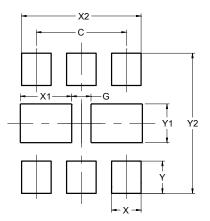
	X2-DFN1010-6							
(Type UXC)								
Dim	Min	Max	Тур					
Α	-	0.40	0.39					
A1	-	0.05						
A3		-	0.127					
b	0.13	0.23	0.18					
D	0.95	1.05	1.00					
D2	0.30	0.40	0.35					
Е	0.95	1.05	1.00					
E2	0.20	0.30	0.25					
е	0.	350 BS	С					
L	0.115	0.215	0.165					
k			0.20					
z	0.02	0.08	0.05					
aaa	0.08							
bbb		0.07						
CCC	0.05							
All	Dimensi	ions in	mm					

X2-DFN1010-6 (Type UXC)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1010-6 (Type UXC)



Dimensions	Value (in mm)
С	0.700
G	0.300
Х	0.230
X1	0.450
X2	0.930
Y	0.250
Y1	0.300
Y2	1.085



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